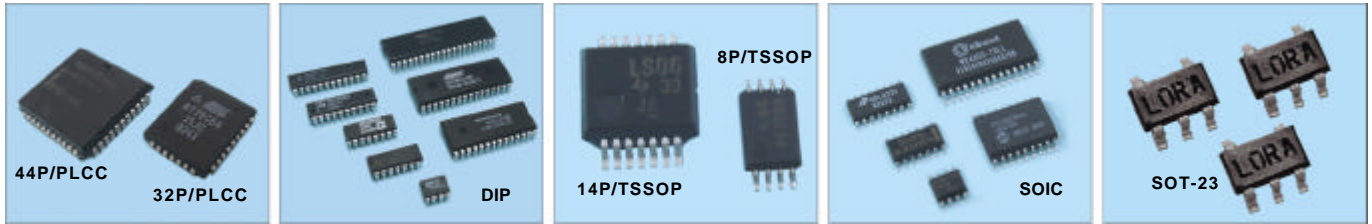


MEMORY IC



| PartNo. | ProductNo. | Manuf. | Description | Organisation | Bus Configuration | Volt.(Vcc) | Size(bits) | Pins/Package |
|---------|----------------------|-----------|----------------------------------------------------------|-----------------|------------------------|------------|------------|--------------|
| 22515 | CAT93C56S-2.7 | CATALYST | 2K-bit Serial EEPROM memory devices | | | 1.8~6.0V | 2K*8or16 | 8P/SOIC |
| 18738 | CAT93C66P | CATALYST | 4K Bit Microwire Serial EEPROM | | | 1.8V | 4 K | 8P/DIP |
| 18739 | CAT93C66S | CATALYST | 4 K Bit Microwire Serial EEPROM | | | 1.8V | 4 K | 8P/SOIC |
| 22516 | CAT93C86S-TE13 | CATALYST | Microwire Serial EEPROM | | | 1.8~6.0V | 16K*8or16 | 8P/SOIC |
| 23550 | FM27C040Q120 | Fairchild | High Performance CMOS EPROM | 512K*8 | | -0.6~7V | | 32P/DIP |
| 18755 | HT24LC02 | HOLTEK | 2K 2-Wire CMOS Serial EEPROM | 256*8 | 2 wire serial | 2.4~5.5V | 2 K | 8P/DIP |
| 27929 | HT93LC46-B | HOLTEK | EEPROM | 64*16 | Serial/O | 3~5V | 1 K | 8P/SOP |
| 18756 | KM93C46GD | SAMSUNG | 1024-bits serial electrically erasable PROM | | | 5V | 1024 | 8P/SOP |
| 22687 | M24C01-WDW6T | ST(SGS) | Bus EEPROM | 128*8 | 2 wire serial | 2.5~5.5V | 1 K | 8P/TSSOP |
| 22698 | M28C64-20K6 | ST(SGS) | Parallel EEPROM with Software Data Protection | 8K*8 | | 5V | 64K | 32P/PLCC |
| 22699 | M28C64C-200K1 | ST(SGS) | Parallel EEPROM | 8K*8 | | 5V | 64K | 32P/PLCC |
| 1538 | M9306B | ST(SGS) | EEPROM(同NM9306N) SGS-Thomson | 16*16 | Serial/O | 5V | 256K | 8P/DIP |
| 22703 | M93C46-MN6 | ST(SGS) | Serial Microwire Bus EEPROM | 1K*8or16 | | 4.5~5.5V | 1 K | 8P/SOP |
| 18757 | NM24C08LM8X | NEC | 2-Wire Bus Interface Serial EEPROM | | 2 wire serial | 2.4~5.5V | 8 K | 8P/SOIC |
| 22774 | NM93C06M8 | N.S | Serial EEPROM | | | 4.5~5.5V | 256Bits | 8P/SOP |
| 18759 | S93CC46BD-J8T1 | SII | 1K-bit serial EEPROM | 64*16 | | | 1 K | 8P/SOP |
| 23603 | SST29EE020-120-4C-NH | SST | Page-Mode EEPROM | 256K*8 | | 5.0V | 2 M | 32P/PLCC |
| 22840 | ST24LW21FB6 | ST(SGS) | Dual Mode Serial Eeprom For Vesa Plug&Play | 128*8 | 2 wire serial | 3.6~5.5V | 1Mbit | 8P/DIP |
| 23610 | TC58V64BFT | TOSHIBA | CMOS NAND EEPROM | 8M*8 BIT | | 2.7~3.6V | 64M | 44P/TSOP |
| 23546 | X24645 | XICOR | Advanced 2-Wire Serial EEPROM with Block Lock Protection | 8*8192 | 2-wire serial | 2.7~5.5V | 64Kbit | 8P-SOIC |
| 23151 | X24C02S8-3T | XICOR | Serial EEPROM | 256*8 Bit | 2 wire serial | 2.7~5.5V | 2 M | 8P/SOIC |
| 19109 | X24C44P | XICOR | CMOS Serial NOVRAM | 16*16(256B) | Serial Port Compatible | 5V 10% | 256BIT | 8P-DIP |
| 20244 | X24C44S | XICOR | CMOS Serial NOVRAM | 16*16(256B) | Serial Port Compatible | 5V 10% | 256BIT | 8P-SOIC |
| 18794 | X2816CP-20 | XICOR | 5 Volt, Byte Alterable EEPROM | 2K*8 | | 5V | 16K | 24P/DIP |
| 18809 | X28C16J | EXEL | PCMCIA Nonvolatile Attribute Memory | 2K*8 | | 5V | 16K | 32P/PLCC |
| 13196 | X28C64P-20 | XICOR | 64K (8K x 8bit) 5 volt, byte alterable EEPROM | 8K*8 | 3 wire serial | 5V | 64K | 28P/DIP |
| 18807 | XL93LC56JR | | 2K2.5V Microwire Serial EEPROM | 256*8 or 128*16 | 3 wire serial | 2.5V | 2048 | SMD |
| 1544 | XL93LC66F | EXEL | EEPROM | 256*16 | 3 wire serial | 5V | 4 K | 8P/SOP |
| 18808 | XL93LC66Y | EXEL | Microchip 3-Wire Interface Serial EEPROMs | 512*8 or 256*16 | 3 wire serial | 2.5V | 4096 | 8P/SOIC |

靜態式記憶體 SRAM

詳細產品規格--請點擊www.100y.com.tw

| PartNo. | ProductNo. | Manuf. | Description | Size | Organisation | Access time | Pins/Package |
|---------|---------------------|--------|------------------------------------------------|-------|--------------|-------------|----------------|
| 19030 | BS62LV1024SC-70 | BSI | Very Low Power/voltage CMOS SRAM | 1M | 128K*8 | 70ns | 32P/SOP |
| 19032 | BS62LV2001SC-70 | BSI | Very Low Power/Voltage CMOS SRAM | | 256K*8 | 70ns | 32P/SOP |
| 19034 | BS62LV256PC-70 | BSI | Very Low Power/Voltage CMOS SRAM | | 32K*8 | 70ns | 28P/PDIP |
| 19035 | BS62LV256SC-70 | BSI | Very Low Power/Voltage CMOS SRAM | | 32K*8 | 70ns | 28P/SOP |
| 14092 | BS62LV256TC-70 | BSI | Very Low Power/voltage CMOS SRAM | 256K | 32K*8 | 70ns | 28P/TSOP |
| 1581 | CXK581000AM-70SL | SONY | 131072-word x 8-bit High Speed CMOS Static RAM | 1M | 131072*8 | 70ns | 32P/SOP |
| 19036 | CXK581000ATM-10LL | SONY | 256K-SRAM | 256K | 32768*8 | 100ns | 32P/TSOP |
| 19037 | CXK581000ATM-10SL | SONY | 256K-SRAM SUPER LOW POWER | 256K | 32768*8 | 100ns | 32P/TSOP |
| 19038 | CXK581000ATM-70LL | SONY | 256K-SRAM SUPER LOW POWER | 256K | 32768*8 | 70ns | 32P/TSOP |
| 19039 | CXK581001M-70L | SONY | SRAM | 1M | | 70ns | SMD |
| 1583 | CXK5816M-15L | SONY | 16K-SRAM | 16K | 2048*8 | 150ns | 24P/SOP |
| 19040 | CXK5816MA-15L | SONY | SRAM | 16K | 2K*8 | 150ns | 24P-SMD |
| 1589 | CXK58257ASP-120ns | SONY | 256K-SRAM | 256K | 32768*8 | 120ns | 28P/DIP-300mil |
| 19041 | CXK58257ATM-10L | SONY | 256K-SRAM | 256K | 32768*8 | 100ns | 28P/TSOP |
| 19042 | CXK58257ATM-10LL | SONY | 256K-SRAM | 256K | 32768*8 | 100ns | 28P/TSOP |
| 19043 | CXK58257ATM-10LLX | SONY | 256K-SRAM | 256K | 32768*8 | 100ns | 28P/TSOP |
| 19044 | CXK58257ATM-10LX | SONY | 256K-SRAM | 256K | 32768*8 | 100ns | 28P/TSOP |
| 1586 | CXK58257ATM-12LL | SONY | 256K-SRAM | 256K | 32768*8 | 120ns | 28P/SOIC |
| 19045 | CXK58257BM-10LL | SONY | SRAM | 256K | 32768*8 | 100ns | SMD |
| 23544 | CXK58257CM-70LL | SONY | High Speed CMOS Static RAM | 32768 | word*8bit | 70ns | 28P/SOIC |
| 19046 | CXK584000YM-70LL | SONY | SRAM | 4M | | | TSOP |
| 1590 | CXK5864CP-10LL | SONY | 64K-SRAM | 64K | 8192*8 | 100ns | 24P/DIP |
| 19047 | CXK5T81000ATM-10LLX | SONY | SRAM | | | 100ns | TSOP |

